NSN 5962-01-512-0677

Memory Microcircuit - Page 1 of 1



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Between 0.189 inches and 0.196 inches

Body Width:

Between 0.150 inches and 0.157 inches

Body Height:

Between 0.042 inches and 0.057 inches

Operating Tempurature Range:

-40.0/+85.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Nha circuit card pn 61-41712-003 cage 00724, component of pn 03-07526-001 cage 00724, used in amplifier radio frequency nsn 5996-01-494-7975, e/i e-3 sentry aircraft

Features Provided:

Electrostatic sensitive and low voltage and cascadable

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Current Rating Per Characteristic:

5.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable

Product Name:

2 wire serial eeprom

Voltage Rating And Type Per Characteristic:

1.8 volts power source and 5.5 volts power source

Memory Device Type:

Eeprom

Memory Capacity:

2k x 8

Special Features:

Endurance: 1 million write cycles, data retention: 100 years, write cycle time: 10ms max

Terminal Type And Quantity:

8 gullwing

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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